

# 2STBN15D100

## Low voltage NPN power Darlington transistor

### Features

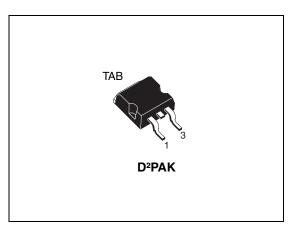
- Good h<sub>FE</sub> linearity
- High f<sub>T</sub> frequency
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

## **Application**

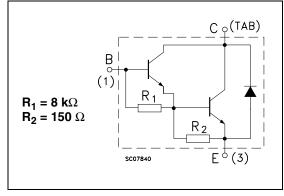
■ Linear and switching industrial equipment

## Description

The device is manufactured in planar technology with "base island" layout and monolithic Darlington configuration.



#### Figure 1. Internal schematic diagrams



Order code	Marking	Package	Packaging
2STBN15D100T4	BN15D100	D <sup>2</sup> PAK	Tape and reel

#### Doc ID 16117 Rev 2

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# 1 Electrical ratings

Table 2.	Absolute	maximum	ratings
	Absolute	maximum	raungs

Symbol	Parameter	Value	Unit				
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	100	V				
V <sub>CEO</sub>	Collector-emitter voltage $(I_B = 0)$	100	V				
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ )	5	V				
Ι <sub>C</sub>	Collector current	12	А				
I <sub>CM</sub>	Collector peak current	15	А				
Ι <sub>Β</sub>	Base current	0.2	А				
P <sub>TOT</sub>	Total dissipation at $T_{case}$ = 25 °C	70	W				
T <sub>STG</sub>	Storage temperature	-65 to 150	°C				
TJ	Max. operating junction temperature	150	°C				

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case max.	1.8	°C/W



# 2 Electrical characteristics

 $T_{case} = 25$  °C; unless otherwise specified.

Table 4. Electrical characteristics
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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = 100 V		-	100	μA
I <sub>CEO</sub>	Collector cut-off current $(I_B = 0)$	V <sub>CE</sub> = 50 V		-	100	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V	0.12	-	2	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA	100	-		V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = 0.5 \text{ A} \qquad I_{B} = 1 \text{ mA}$ $I_{C} = 4 \text{ A} \qquad I_{B} = 4 \text{ mA}$		-	1.5 1.3	V V
V <sub>BE(on)</sub> <sup>(1)</sup>	Base-emitter on voltage	$I_{\rm C} = 3 \text{ A}$ $V_{\rm CE} = 3 \text{ V}$		-	2.5	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_{\rm C} = 3  {\rm A}$ $V_{\rm CE} = 3  {\rm V}$	750	-		
V <sub>F</sub>	Diode forward voltage	I <sub>F</sub> = 3 A		-	2.5	V

1. Pulse test: pulse duration  $\leq$  300 µs, duty cycle  $\leq$  2 %.



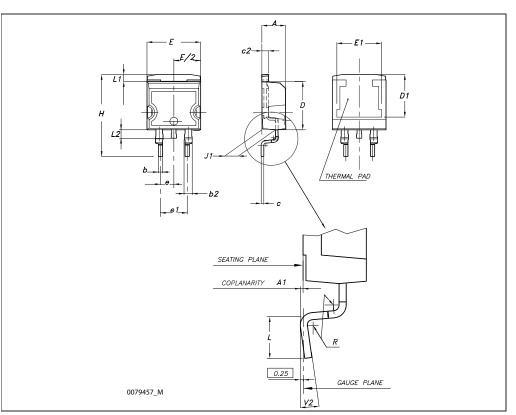
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



Dim		mm	inch			
Dim	Min	Тур	Max	Min	Тур	Max
Α	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
е		2.54			0.1	
e1	4.88		5.28	0.192		0.208
Н	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°

#### D<sup>2</sup>PAK (TO-263) mechanical data





# 4 Revision history

Table 5.Document revision history

Date	Revision	Changes
01-Sep-2009	1	First release.
19-Jan-2010	2	Modified Table 1 on page 1.



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